

# Thyristor/Thyristor (Super MAGN-A-PAK Power Modules), 570 A



Super MAGN-A-PAK

PRIMARY CHARACTERISTICS				
I <sub>T(AV)</sub>	570 A			
Туре	Modules - thyristor, standard			
Package	Super MAGN-A-PAK			

#### **FEATURES**

- High current capability
- High surge capability
- · Industrial standard package
- 3000 V<sub>RMS</sub> isolating voltage with non-toxic substrate
- · Designed and qualified for industrial level
- UL approved file E78996
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>

#### **TYPICAL APPLICATIONS**

- Motor starters
- DC motor controls AC motor controls
- Uninterruptible power supplies

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I <sub>T(AV)</sub>	T <sub>C</sub> = 74 °C	570			
I <sub>T(RMS)</sub>	T <sub>C</sub> = 74 °C	895	A		
I <sub>TSM</sub>	50 Hz	17 800	^		
	60 Hz	18 700			
l <sup>2</sup> t	50 Hz	1591	kA <sup>2</sup> s		
1-1	60 Hz	1452	KA <sup>2</sup> S		
I <sup>2</sup> √t		15 910	kA <sup>2√</sup> s		
V <sub>RRM</sub>	Range	1800	V		
T <sub>Stg</sub>	Range	-40 to +135	°C		
T <sub>J</sub>	Range	-40 to +135			

#### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> /V <sub>DRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$\begin{aligned} I_{RRM}/I_{DRM} & \text{MAXIMUM} \\ \text{AT T}_{J} &= T_{J} & \text{MAXIMUM} \\ & \text{mA} \end{aligned}$		
VS-VSKT570-18PbF	18	1800	1900	120		



ON-STATE CONDUCTION						
PARAMETER	SYMBOL		TEST CONDI	TIONS	VALUES	UNITS
Maximum average on-state current	L	180° conduction	n, half sine wave			Α
at case temperature	I <sub>T(AV)</sub>	180 Conduction	i, iiali siile wave			°C
Maximum RMS on-state current	I <sub>T(RMS)</sub>	180° conduction	n, half sine wave	at T <sub>C</sub> = 74 °C	895	Α
		t = 10 ms	No voltage		17.8	
Maximum peak, one-cycle,	I <sub>TSM,</sub>	t = 8.3 ms	reapplied		18.7	kA
non-repetitive on-state surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		15.0	
	t = 8.3 ms reapplied Sinusoidal	Sinusoidal half wave.	15.7			
		t = 10 ms	No voltage reapplied	initial $T_J = T_J$ maximum	1591	- kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	t = 8.3 ms			1452	
waxiinum i-t for fusing		t = 10 ms	100 % V <sub>RRM</sub>		1125	
		t = 8.3 ms	reapplied		1027	
Maximum $I^2\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10	ms, no voltage r	eapplied	15 910	kA²√s
Low level value or threshold voltage	V <sub>T(TO)1</sub>	$(16.7 \% \times \pi \times I_{T})$	$AV < I < \pi \times I_{T(AV)}$	$T_{J} = T_{J}$ maximum	0.864	V
High level value of threshold voltage	V <sub>T(TO)2</sub>	$(I > \pi \times I_{T(AV)}), T_J$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			v
Low level value on-state slope resistance	r <sub>t1</sub>	(16.7 % x $\pi$ x $I_{T(AV)}$ < $I$ < $\pi$ x $I_{T(AV)}$ ), $T_J = T_J$ maximum			0.411	mΩ
High level value on-state slope resistance	r <sub>t2</sub>	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.362	11152
Maximum on-state voltage drop	$V_{TM}$	$I_{pk}$ = 1500 A, $T_J$ = 25 °C, $t_p$ = 10 ms sine pulse			1.50	V
Maximum holding current	I <sub>H</sub>	T. = 25 °C 222	do supply 12 V ro	sistiva load	500	mA
Maximum latching current	ΙL	1j = 25 C, and	T <sub>J</sub> = 25 °C, anode supply 12 V resistive load		1000	IIIA

SWITCHING					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum rate of rise of turned-on current	dl/dt	$T_J = T_J$ maximum, $I_{TM} = 400$ A, $V_{DRM}$ applied	1000	A/µs	
Typical delay time	t <sub>d</sub>	Gate current 1 A, $dI_g/dt = 1 A/\mu s$ $V_d = 0.67 \% V_{DRM}$ , $T_J = 25 °C$	2.0		
Typical turn-off time	t <sub>q</sub>	$I_{TM}$ = 750 A; $T_J$ = $T_J$ maximum, dl/dt = - 60 A/μs, $V_R$ = 50 V, dV/dt = 20 V/μs, gate 0 V 100 $\Omega$	200	μs	

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, linear to $V_D = 80 \% V_{DRM}$	1000	V/µs
RMS insulation voltage	V <sub>INS</sub>	t = 1 s	3000	V
Maximum peak reverse and off-state leakage current	I <sub>RRM</sub> , I <sub>DRM</sub>	$T_J = T_J$ maximum, rated $V_{DRM}/V_{RRM}$ applied	120	mA



TRIGGERING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum peak gate power	$P_{GM}$	$T_J = T_J$ maximum, $t_p \le 5$ ms	10	W
Maximum peak average gate power	P <sub>G(AV)</sub>	$T_J = T_J$ maximum, f = 50 Hz, d % = 50	2.0	] vv
Maximum peak positive gate current	+I <sub>GM</sub>		3.0	Α
Maximum peak positive gate voltage	+V <sub>GM</sub>	$T_J = T_J$ maximum, $t_p \le 5$ ms	20	V
Maximum peak negative gate voltage	-V <sub>GM</sub>		5.0	
Maximum DC gate current required to trigger	I <sub>GT</sub>	T 05 °C V 10 V	200	mA
DC gate voltage required to trigger	V <sub>GT</sub>	T <sub>J</sub> = 25 °C, V <sub>ak</sub> 12 V	3.0	V
DC gate current not to trigger	$I_{GD}$	$T_J = T_J$ maximum	10	mA
DC gate voltage not to trigger	$V_{GD}$		0.25	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	TJ		-40 to +135	°C	
Maximum storage temperature range	T <sub>Stg</sub>		-40 to +135		
Maximum thermal resistance, junction to case per junction	R <sub>thJC</sub>	DC operation	0.065	14004	
Maximum thermal resistance, case to heatsink per module	R <sub>thC-hs</sub>	Mounting surface smooth, flat and greased	0.02	2 K/W	
Mounting Super MAGN-A-PAK to heatsing	nk	A mounting compound is recommended and the torque should be rechecked after a period	6 to 8	Nm	
torque busbar to super MAGN-A-PA	K	of 3 hours to allow for the spread of the compound	12 to 15	INIII	
Approximate weight			1500	g	
Case style		See dimensions (link at the end of datasheet)	Super MAGN-	-A-PAK	

△R <sub>thJC</sub> CONDUCTIO	N			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.009	0.006		
120°	0.011	0.011		
90°	0.014	0.015	$T_J = T_J$ maximum	K/W
60°	0.021	0.022		
30°	0.037	0.038		

#### Note

• Table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



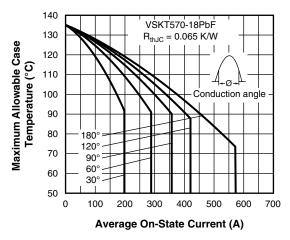


Fig. 1 - Current Ratings Characteristics

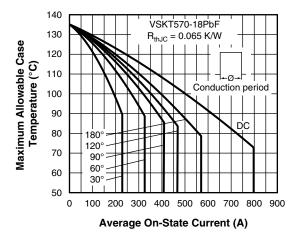


Fig. 2 - Current Ratings Characteristics

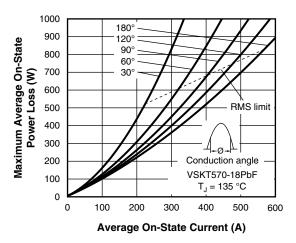


Fig. 3 - On-State Power Loss Characteristics

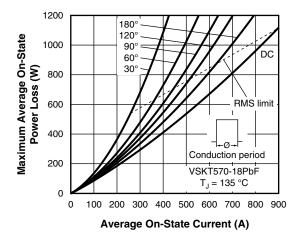


Fig. 4 - On-State Power Loss Characteristics

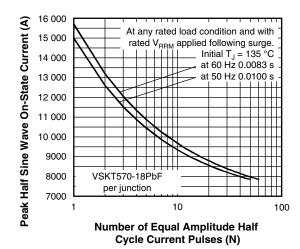


Fig. 5 - Maximum Non-Repetitive Surge Current

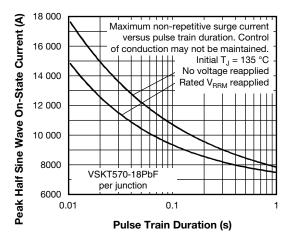
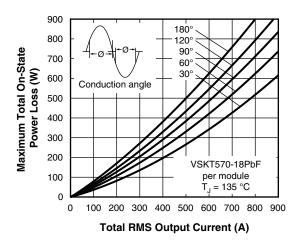


Fig. 6 - Maximum Non-Repetitive Surge Current



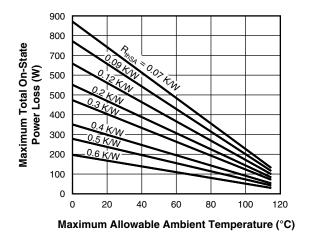


Fig. 7 - On-State Power Loss Characteristics

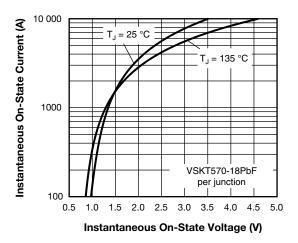


Fig. 8 - On-State Voltage Drop Characteristics

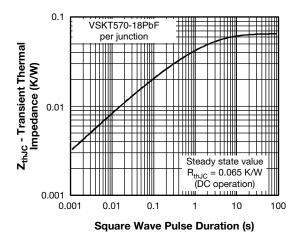


Fig. 9 - Thermal Impedance Z<sub>thJC</sub> Characteristics

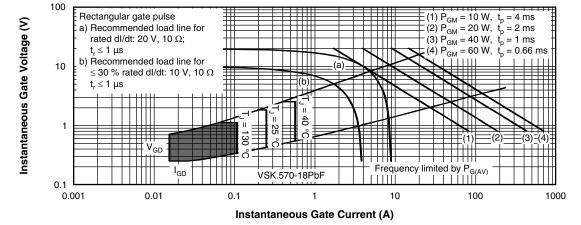
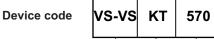
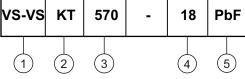


Fig. 10 - Gate Characteristics

#### **ORDERING INFORMATION TABLE**





Vishay Semiconductors product

Circuit configuration (see below)

Current rating

Voltage code x 100 = V<sub>RRM</sub>

Lead (Pb)-free

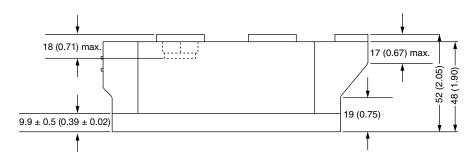
CIRCUIT CONFIGURATION	CIRCLUT CONFICURATION CORE	CIDCUIT DRAWING
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	VSKT
wo SCRs doubler circuit	KT	4 (K1) 7 (K2) 5 (G1) 6 (G2)

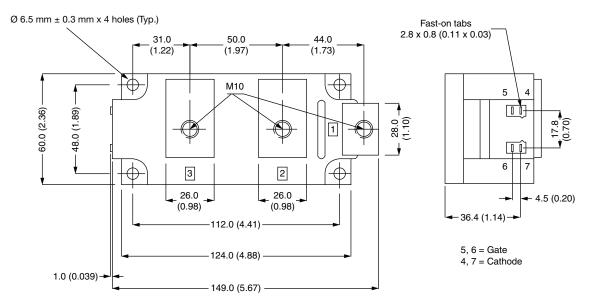
LINKS TO RELAT	ED DOCUMENTS
Dimensions	www.vishay.com/doc?95283



# **Super MAGN-A-PAK Thyristor/Diode**

### **DIMENSIONS** in millimeters (inches)







## **Legal Disclaimer Notice**

Vishay

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